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Vishay General Semiconductor

Surface Mount PAR® Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions





PRIMARY CHARACTERISTICS					
V_{WM}	10 V to 36 V				
V_{BR}	11.1 V to 44.2 V				
P _{PPM} (10 x 1000 μs)	4600 W				
P _{PPM} (10 x 10 000 μs)	3600 W				
P_{D}	6 W				
I _{FSM}	600 A				
T _J max.	175 °C				
Polarity	Unidirectional				
Package	DO-218AB				

FEATURES

 Junction passivation optimized design passivated anisotropic rectifier technology



- T_{.I} = 175 °C capability suitable for high reliability COMPLIANT and automotive requirement
- Available in unidirectional polarity only
- Low leakage current
- Low forward voltage drop
- · High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AB

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3 X - RoHS-compliant and AEC-Q101 qualified ("X" denotes revision code e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation	with 10/1000 µs waveform	В	4600	W		
	with 10/10 000 µs waveform	P _{PPM}	3600			
Power dissipation on infinite heat	P _D	6.0	W			
Peak pulse current with 10/1000	I _{PPM} ⁽¹⁾	See next table	Α			
Peak forward surge current 8.3 m	I _{FSM}	600	Α			
Operating junction and storage te	T _J , T _{STG}	-55 to +175	°C			

Note

 $^{(1)}$ Non-repetitive current pulse at $T_A = 25~^{\circ}C$

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SM6S10A thru SM6S36A

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)										
DEVICE TYPE	BREAKDOWN VOLTAGE V _{BR} (V)		TEST CURRENT	STAND-OFF VOLTAGE	MAXIMUM REVERSE LEAKAGE	MAXIMUM REVERSE LEAKAGE	MAX. PEAK PULSE CURRENT AT 10/1000 µs	MAXIMUM CLAMPING VOLTAGE	TYPICAL TEMP. COEFFICIENT OF V _{BR} ⁽¹⁾	
TIPE	MIN.	NOM.	MAX.	I _T (mA)	V _{WM} (V)	AT V _{WM} I _D (μA)	A! VWM T 175°C	WAVEFORM (A)	AVEFORM AI IPPM	αT (%/°C)
SM6S10A	11.1	11.7	12.3	5.0	10.0	15	250	271	17.0	0.069
SM6S11A	12.2	12.9	13.5	5.0	11.0	10	150	253	18.2	0.072
SM6S12A	13.3	14.0	14.7	5.0	12.0	10	150	231	19.9	0.074
SM6S13A	14.4	15.2	15.9	5.0	13.0	10	150	214	21.5	0.076
SM6S14A	15.6	16.4	17.2	5.0	14.0	10	150	198	23.2	0.078
SM6S15A	16.7	17.6	18.5	5.0	15.0	10	150	189	24.4	0.080
SM6S16A	17.8	18.8	19.7	5.0	16.0	10	150	177	26.0	0.081
SM6S17A	18.9	19.9	20.9	5.0	17.0	10	150	167	27.6	0.082
SM6S18A	20.0	21.1	22.1	5.0	18.0	10	150	158	29.2	0.083
SM6S20A	22.2	23.4	24.5	5.0	20.0	10	150	142	32.4	0.085
SM6S22A	24.4	25.7	26.9	5.0	22.0	10	150	130	35.5	0.086
SM6S24A	26.7	28.1	29.5	5.0	24.0	10	150	118	38.9	0.087
SM6S26A	28.9	30.4	31.9	5.0	26.0	10	150	109	42.1	0.088
SM6S28A	31.1	32.8	34.4	5.0	28.0	10	150	101	45.4	0.089
SM6S30A	33.3	35.1	36.8	5.0	30.0	10	150	95	48.4	0.090
SM6S33A	36.7	38.7	40.6	5.0	33.0	10	150	86	53.3	0.091
SM6S36A	40.0	42.1	44.2	5.0	36.0	10	150	79	58.1	0.091

Notes

⁽¹⁾ To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at $T_J = V_{BR}$ at 25 °C x (1 + α T x (T_J - 25))

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	VALUE	UNIT		
Typical thermal resistance, junction to case	$R_{\theta JC}$	0.95	°C/W		

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SM6S10AHE3_A/I (1)	2.550	I	750	13" diameter plastic tape and reel, anode towards the sprocket hole		

Note

(1) AEC-Q101 qualified

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[•] For all types maximum V_F = 1.9 V at I_F = 100 A measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

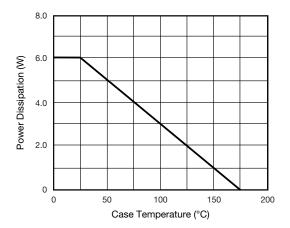


Fig. 1 - Power Derating Curve

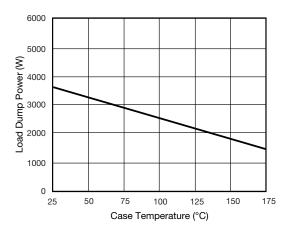


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)

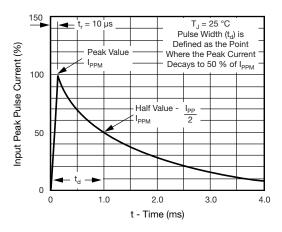


Fig. 3 - Pulse Waveform

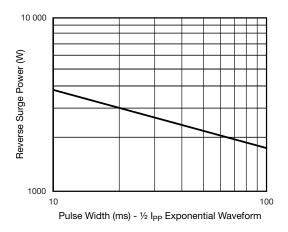


Fig. 4 - Reverse Power Capability

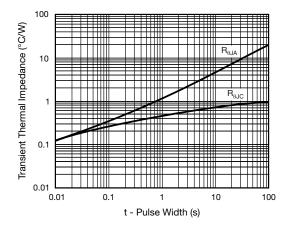
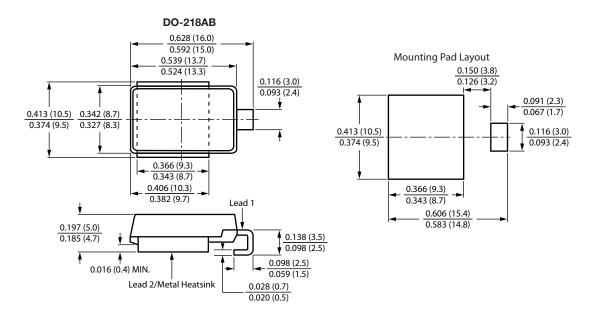


Fig. 5 - Typical Transient Thermal Impedance



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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